

isc Silicon NPN Power Transistors

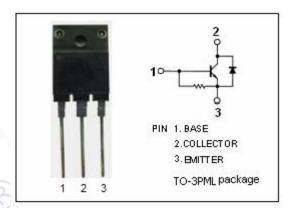
BU508DF

DESCRIPTION

- · High Switching Speed
- · High Voltage
- · Built-in Integrated Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

 Designed for use in horizontal deflection circuits of colour TV receivers.

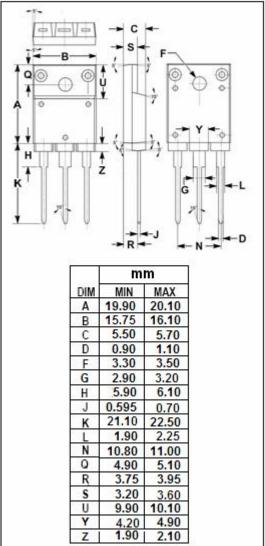


ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	1500	V
V _{CEO}	Collector-Emitter Voltage	700	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	8	А
I _{CM}	Collector Current-Peak	15	А
I _B	Base Current	4	А
I _{BM}	Base Current-Peak	6	А
Pc	Collector Power Dissipation @T _C =25°C	34	W
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-65~150	$^{\circ}$ C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.7	K/W



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	Ic= 50mA ;I _B = 0	700			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 4.5A; I _B = 1.6A			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 4.5A ;I _B = 2A			1.1	V
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C =0	8.		300	mA
I _{CES}	Collector Cutoff Current	V _{CB} = BV _{CBO} ;I _E = 0 V _{CB} = BV _{CBO} ;I _E = 0;T _C =125°C		%	1.0 2.0	mA
h _{FE}	DC Current Gain	Ic= 0.1A; Vc== 5V	6		30	
fτ	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 5V		7		MHz
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V;f _{test} = 1MHz		125		pF
V _{ECF}	C-E Diode Forward Voltage	I _F = 4.5A		1.6	2.0	V

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